

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

NPN Transistors

6501130 NATL SEMICOND. (DISCRETE)



LOW LEVEL AMPS

1-10

Type No.	Case Style	VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICBO (nA) @ VCB Max	VCB (V)	hFE @ IC & VCE			VCE(SAT) (V) & VBE(SAT) (V) @ IC			Cob (pF) Max	fT (MHz) @ IC		NF (dB) Max	Test Conditions	Process No.				
							Min	Max	@	Min	Max	@		Min	Max				Min	Max		
2N760	TO-18	45	45	8	200	30	76	300	1	5	1.0	0.6	1.1	10	8	50	1.0		07			
2N760A	TO-18	60	60	8	100	30	76	333	1	5	1.0		1.1	10	8	50	1.0		07			
2N929	TO-18	45	45	5	10	45	60	350	10	5	1.0	0.6	1.0	10	8	30	0.5	4	1	07		
2N929A	TO-18	60	45	6	2	45	60	350	10	5	0.5	0.7	0.9	10	6	45	0.5	4		07		
2N930	TO-18	45	45	5	10	45	150	600	10	5	1.0	0.6	1.0	10	8	30	0.5	3	1	07		
2N2484	TO-18	60	60	6	10	45	250	200	1	5	0.35			1	10	15	0.05	3	1	07		
2N2509	TO-18	125	80	7	5	100	40	25	10	5	1.0		0.9	5	6	45	5	7	1	07		
2N2510	TO-18	100	65	7	5	80	150	75	500	10	5	1.0		0.9	5	6	45	5	4	2	07	
2N2511	TO-18	80	50	7	5	60	240	120	750	10	5	1.0		0.9	5	6	45	5	4	2	07	
2N2586	TO-18	60	45	6	2	45	150	120	600	10	5	0.5	0.7	0.9	10	7	45	0.5	3.5	2	07	
2N3117	TO-18	60	60	6	10	45	400	300	1	5	0.35			1	4.5	60	0.5	1	2	07		
2N3246	TO-18	60	40	10	1	40	400	350	800	10	5	0.5	0.7	0.9	5	5	60	180	1	2	1	07

28C 35395
 7-29-01

0

**LOW LEVEL AMPS** (Continued)

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

6501130 NATL SEMICON, (DISCRETE)

Type No.	Case Style	V _{CB0} (V) Min	V _{CEO} (V) Min	V _{EB0} (V) Min	I _{CBO} (nA) Max	V _{CB} (V)	h _{FE} @ I _C & V _{CE} (V)		V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) @ I _C (mA)		C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		NF (dB) Max	Test Conditions	Process No.			
							Min	Max		Min	Max		Min	Max				Min	Max	
2N3565	TO-92 (92)	Same as PN3565, see page 1-13 for explanation															07			
2N3707	TO-92 (94)	30	30	6	100	20	100	400	100 μA	5	1.0	10			5	1	07			
2N3708	TO-92 (94)	30	30	6	100	20	45	660	1	5	1.0	10					07			
2N3709	TO-92 (94)		30		100	20	45	165	1	5	1.0	10					07			
2N3710	TO-92 (94)	30	30	6	100	20	90	330	1	5	1.0	10					07			
2N3711	TO-92 (94)	30	30	6	100	20	180	660	1	5	1.0	10					07			
2N3858A	TO-92 (94)	60	60	6	500	18	60	120	10	1		4	90	250	2		07			
2N3859A	TO-92 (94)	60	60	6	500	18	100	200	10	1		4	90	250	2		07			
2N3877	TO-92 (94)	70	70	4	500	70	20	250	2	4.5	0.5	0.9	10				07			
2N3877A	TO-92 (94)	85	85	4	500	70	20	250	2	4.5	0.5	0.9	10				07			
2N3900A	TO-92 (94)	18	18	5	100	18	250	500	2	4.5		12			5	4	07			
2N3901	TO-92 (94)	18	18	5	100	15	350	700	2	4.5					5	4	07			
2N4286	TO-92 (94)	30	25	6	50	25	150	600	1	5	0.35	0.8	1	6	40	1	07			
2N4287	TO-92 (94)	45	45	7	10	30	150	600	1	5	0.35	0.8	1	6	40	1	07			
2N4384	TO-18	40	30	5	10	30	150	10	5	0.2	0.65	0.8	10	8	30	120	0.5	2	1	07
2N4386	TO-18	40	30	5	10	30	120	10	5	0.2	0.65	0.8	10	8	30	120	0.5	3	1	07
2N4409	TO-92 (92)	80	50	5	10	60	60	400	10	1	0.2	0.8	1	12	60	300	10			07

TEST CONDITIONS:

(1) I_C = 10 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (2) I_C = 10 μA, V_{CE} = 5V, f = 1 kHz. (3) I_C = 5 μA, V_{CE} = 5V, f = 1 kHz. (4) I_C = 100 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (5) I_C = 10 μA, V_{CE} = 5V, f = 10 kHz. (6) I_C = 100 μA, V_{CE} = 5V, f = 5 kHz.

**NPN Transistors**
 28C 35396
 Y-29-01

D

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
 Http://www.100y.com.tw

NPN Transistors

6501130 NATL SEMICONDUCTOR (DISCRETE)

28C 35397 D



LOW LEVEL AMPS (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CEO} (V) Min	V _{EBO} (V) Min	I _{CBO} (nA) Max	V _{CB} (V) @	hFE @ I _C & V _{CE} (V)				V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA)			C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		NF (dB) Max	Test Conditions	Process No.	
							Min	Max	Min	Max	Max	Min	Max		Min	Max				
2N4410	TO-92 (92)	120	80	5	10	100	60	400	10	1	0.2	0.8	1	12	60	300	10			07
2N4966	TO-92 (92)	50	40	6	25	25	40	200	0.01	5	0.4		10	6	40	1				07
2N4967	TO-92 (92)	50	40	6	25	25	100	600	0.01	5	0.4		10	6	40	1				07
2N4968	TO-92 (92)	30	25	6	50	25	40	200	0.01	5	0.4		10	6						07
2N5088	TO-92 (92)	35	30		50	20	300		10	5	0.5		10	4			3	3		07
2N5089	TO-92 (92)	30	25		50	15	400		10	5	0.5		10	4			2	3		07
2N5133	TO-92 (92)	20	18	3	50	15	60	1000	1 mA	5	0.4		1	5						07
2N5209	TO-92 (92)	50	50		50	35	150		10	5	0.7		10	4	30	0.5	4	5		07
2N5210	TO-92 (92)	50	50		50	35	250		10	5	0.7		10	4	30	0.5	3	4		07
2N5232	TO-92 (94)		50		30	50	250	500	2	5	0.125		10	4						07
2N5232A	TO-92 (94)		50		30	50	250	500	2	5	0.125		10	4			5	2		07
MPS3707	TO-92 (92)		30		100	20	100	400	100 μA	5	1.0		10				5	4		07
MPS3708	TO-92 (92)		30		100	20	45	660	1	5	1.0		10							07
MPS3709	TO-92 (92)		30		100	20	45	165	1	5	1.0		10							07
MPS3710	TO-92 (92)		30		100	20	90	330	1	5	1.0		10							07
MPS3711	TO-92 (92)		30		100	20	180	660	1	5	1.0		10							07
MPS6571	TO-92 (92)	25	20	3	50	20	250	1000	100 μA	5	0.5		10	4.5	50	0.5				07
MPSA09	TO-92 (92)	50	50		100	25	100	600	100 μA	5	0.9		10	5	600	0.5				07

T-29-01

1-12

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)



LOW LEVEL AMPS (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) Max @ V _{CB} (V)	h _{FE} @ I _C & V _{CE} (V)				V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA)			C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		NF (dB) Max	Test Conditions	Process No.	
						Min	Max	I _C (mA)	V _{CE} (V)	Max	Min	Max		Min	Max				
PE4010	TO-92 (92)	30	25	6	200 5	200	1000	1	10	0.35		1	4	20 60	0.05 1			07	
PN930	TO-92 (92)	45	45	5	10 45	600	10	5	5	1.0	0.6	1.0	10	8	30	0.5	3	1	07
PN2484	TO-92 (92)	60	60	6	10 45	800	10	5	5	0.35		10	6					07	
PN3565	TO-92 (92)	30	25	6	50 25	150	600	1	10	0.35		1	4	40	240	1		07	
PN5133	TO-92 (92)	20	18	3	50 15	60	1000	1	5	0.4		1	5	40	240	1		07	

TEST CONDITIONS:

(1) I_C = 10 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (2) I_C = 10 μA, V_{CE} = 5V, f = 1 kHz. (3) I_C = 5 μA, V_{CE} = 5V, f = 1 kHz. (4) I_C = 100 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (5) I_C = 10 μA, V_{CE} = 5V, f = 10 kHz. (6) I_C = 100 μA, V_{CE} = 5V, f = 5 kHz.

T-13

6501130 NATL SEMICOND, (DISCRETE)

T-29-01



GENERAL PURPOSE AMPS AND SWITCHES

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) Max @ V _{CB} (V)	h _{FE} @ I _C & V _{CE} (V)				V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA)			C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.		
						Min	Max	I _C (mA)	V _{CE} (V)	Max	Min	Max		Min	Max						
MPS3903	TO-92 (92)	60	40	6		20		0.1	1	0.2	0.65	0.85	10	4	200	10		5	8	02	
						35		1	1												
						50	150	10	1												
						30		50	1												
						15		100	1	0.3		1.0	50								

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CC} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CC} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz.

28C 35398

D



NPN Transistors

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

NPN Transistors



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0} (V)	V _{CE0} (V)	V _{EB0} (V)	I _{CB0} (nA) @ V _{CB} (V)	h _{FE} @ I _C & V _{CE}			V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA)			C _{ob} (pF)	f _T (MHz) @ I _C (mA)		t _{off} (ns)	NF (dB)	Test Conditions	Process No.	
		Min	Min	Min	Max	Min	Max	Min	Max	Max	Min	Max	Max	Min	Max	Max			Max
MPS3904	TO-92 (92)	60	40	6		40	0.1	1	0.2	0.65	0.85	10	4	200	10		5	8	02
						70	1	1											
						100	300	10	1										
						60	50	1											
						30	100	1	0.3	1.0	50								
MPS6573	TO-92 (92)		35		100 35	100	100 μA	5	0.5			10	12	100	300	10			02
						200	500	10	5										
MPS6574	TO-92 (92)		35		100 35	100	300	1	0.5			10	12	100	300	10			02
						(4 Groups)													
MPS6575	TO-92 (92)		45		100 45	100	100 μA	5	0.5			10	12	100	300	10			02
						200	500	10	5										
MPS6576	TO-92 (92)		45		100 45	100	300	1	0.5			10	12	100	300	10			02
						(4 Groups)													
MPSA20	TO-92 (92)		40	4	100 30	40	400	5	10				4	125	5				02
2N2923	TO-92 (94)	25	25	5	100 25	90	180	2	10				10						04
2N2924	TO-92 (94)	25	25	5	100 25	150	300	2	10				10						04
2N2925	TO-92 (94)	25	25	5	100 25	235	470	2	10				10						04
2N2926	TO-92 (94)	18	18	5	500 18	35	470	2	10				10						04
2N3390	TO-92 (94)	25	25	5	100 18	400	800	2	4.5				10						04
2N3391	TO-92 (94)	25	25	5	100 18	250	500	2	4.5				10				5	5	04
2N3391A	TO-92 (94)	25	25	5	100 18	250	500	2	4.5				10				5	5	04
2N3392	TO-92 (94)	25	25	5	100 18	150	300	2	4.5				10						04
2N3393	TO-92 (94)	25	25	5	100 18	90	180	2	4.5				10						04
2N3395	TO-92 (94)	25	25	5	100 18	150	500	2	4.5				10						04
2N3396	TO-92 (94)	25	25	5	100 18	90	500	2	4.5				10						04
2N3397	TO-92 (94)	25	25	5	100 18	55	500	2	4.5				10						04

T-29-01

6501130 NATL SEMICOND, (DISCRETE)

28C 35399 D

T-14



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) Max	V _{CB} (V)	h _{FE} @ I _C & V _{CE} (V)			V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) @ I _C (mA)			C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
							Min	Max	@		Min	Max	@		Min	Max				
2N3398	TO-92 (94)	25	25	5	100	18	55	800	2	4.5				10						04
2N3415	TO-92 (94)	25	25	5	100	25	180	540	2	4.5	0.3	0.6	1.3	50						04
2N3416	TO-92 (94)	50	50	5	100	25	75	225	2	4.5	0.3	0.6	1.3	50						04
2N3417	TO-92 (94)	50	50	5	100	25	180	540	2	4.5	0.3	0.6	1.3	50						04
2N3900	TO-92 (94)	18	18	5	100	18	250	500	2	4.5					12					04
2N4424	TO-92 (94)	40	40	5	100	25	180	540	2	4.5	0.3	0.6	1.3	50						04
2N5172	TO-92 (94)	25	25	5	100	25	100	500	10	10	0.25			10						04
MPS3392	TO-92 (92)	25	25	5	100	18	150	300	2	4.5				10						04
MPS3393	TO-92 (92)		25		100	18	90	180	2	4.5				3.5						04
MPS3394	TO-92 (92)		25		100	18	55	110	2	4.5				3.5						04
MPS3395	TO-92 (92)		25		100	18	150	500	2	4.5				3.5						04
MPS3396	TO-92 (92)		25		100	18	90	500	2	4.5				3.5						04
MPS3397	TO-92 (92)		25		100	18	55	500	2	4.5				3.5						04
MPS3398	TO-92 (92)		25		100	18	55	800	2	4.5				3.5						04
MPS5172	TO-92 (92)	25	25	5	100	25	100	500	10	10	0.25			10						04
MPS6520	TO-92 (92)		25	4	50	30	200	400	2	10	0.5			50			3	10		04
MPS6521	TO-92 (92)		25	4	50	30	200	600	2	10	0.5			50			3	10		04
TIS97	TO-92 (97)		40		10	40	250	700	0.1	5							3	7		04

T-29-01

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CC} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CC} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz.

6501130 NATL SEMICOND, (DISCRETE) 28C 35400 0

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)



NPN Transistors

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

NPN Transistors



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICBO (nA) @ VCB (V) Max	hFE @ IC & VCE (V)				VCE(SAT) (V) & VBE(SAT) (V) @ IC (mA)			Cob (pF) Max	fT (MHz) @ IC (mA)		toff (ns) Max	NF (dB) Max	Test Conditions	Process No.			
						Min	Max	Min	Max	Min	Max	Min		Max	Min					Max		
2N3704	TO-92 (94)	50	30	5	100 20	100	300	50	2	0.6		100	12	100	50				13			
2N3705	TO-92 (94)	50	30	5	100 20	50	150	50	2	0.8		100	12	100	50				13			
2N3706	TO-92 (94)	40	20	5	100 20	30	600	50	2	1.0		100	12	100	50				13			
2N3794	TO-92 (94)	40	20	5	500 15	100	600	100	10	0.4		10	10	100	600	10			13			
2N4400	TO-92 (92)	60	40	6		20	500	2	0.4	0.75	0.95	150	6.5	200	20	255		2	13			
						50	150	1														
						40	10	1	0.75		1.2	500										
						20	1	1														
2N4401	TO-92 (92)	60	40	6		40	500	2	0.4	0.75	0.95	150	6.5	250	20	255		2	13			
						100	300	150	1													
						80	10	1	0.75		1.2	500										
						40	1	1														
2N4944	TO-92 (92)	80	40	5	50 40	40	120	150	1	0.25		150	60	900	50			13				
2N4946	TO-92 (92)	80	40	5	50 40	100	300	150	1	0.25		150	60	900	50			13				
2N4951	TO-92 (94)	60	30	5	50 40	60	200	150	10	0.3	1.3	150	8	250	20	400		2	13			
						40	10	10														
						20	1	10														
2N4952	TO-92 (94)	60	30	5	50 40	100	300	150	10	0.3	1.3	150	8	250	20	400		2	13			
						75	10	10														
						50	1	10														
2N4953	TO-92 (94)	60	30	5	50 40	200	600	150	10	0.3	1.3	150	8	250	20	400		2	13			
						150	10	10														
						75	1	10														
2N4954	TO-92 (94)	40	30	5	50 30	60	600	150	10	0.3	1.3	150	8	250	20	400		2	13			
						40	10	10														
						20	1	10														
2N5220	TO-92 (92)	15	15	3	100 10	30	600	50	10	0.5	1.1	150	10	100	20			13				
2N5225	TO-92 (92)	25	25	4	300 15	30	600	50	10	0.8	1.0	100	20	50	20			13				
						25	50	10														
MPS3704	TO-92 (92)	50	30	5	100 20	100	300	50	2	0.6		100	12	100	50			13				

1-16

6501130 NATL SEMICOND. (DISCRETE)

28C 35401 D

Y-29-01



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CE0} (V) Min	V _{CEO} (V) Min	V _{EB0} (V) Min	I _{CBO} (nA) Max	V _{CB} (V)	h _{FE} @ I _C & V _{CE} (V)		V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA)		C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.		
							Min	Max	Max	Min		Max	Min					Max	
MPS3705	TO-92 (92)	50	30	5	100	20	50	150	50	2	0.8	100	50				13		
MPS3706	TO-92 (92)	40	20	5	100	20	30	600	50	2	1.0	100	50				13		
MPS6522	TO-92 (92)		25	4	50	20	100	400	0.1	10	0.5	50					13		
MPS6530	TO-92 (92)	60	40	5	50	40	25	120	500	10	0.5	100					13		
							40	100	100	1									
MPS6531	TO-92 (92)	60	40	5	50	40	50	270	500	10	0.3	100					13		
							60	100	100	1									
MPS6532	TO-92 (92)	50	30	5	100	30	30		100	1	0.5	100					13		
NCBT13	TO-92 (92)	80	40	4	100	30	40		20	1	0.15	100	150	20			13		
PN3566	TO-92 (92)	40	30	5	50	20	80	150	2	10	1	100	40	700	30		13		
							40	600	10	10									
PN3567	TO-92 (92)	80	40	5	50	40	40	120	30	1	0.25	150	60	900	50		13		
							40	150	1	1									
PN3569	TO-92 (92)	80	40	5	50	40	100	300	150	1	0.25	150	60	900	50		13		
							100	30	1	1									
PN5449	TO-92 (92)	50	30	5	100	20	100	300	50	2	0.6	100	100	50			13		
PN5816	TO-92 (92)	50	40	5	100	25	100	200	2	2	0.75	1.2	500	100	50		13		
2N5550	TO-92 (92)	160	140	6	100	100	20	50	5	5	0.15	1.0	10	6	100	300	10	10	8
							60	250	10	5									
							60	1	5	5	0.25	1.2	50						
2N5551	TO-92 (92)	180	160	6	50	120	30	50	5	5	0.15	1.0	10	6	100	300	10	8	8
							80	250	10	5									
							80	1	5	5	0.2	1.0	50						
2N5830	TO-92 (92)	120	100	5	50	100	60	1	5	5	0.15	0.8	1		100	500	10		16
							80	500	10	5	0.2	1	10						
							80	50	5	5	0.25	1	50						

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CC} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CC} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz.

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)



NPN Transistors

6501130 NATL SEMICOND, (DISCRETE)

28C 35402

D

NPN Transistors

6501130 NATL SEMICOND, (DISCRETE)



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CEO} (V) Min	V _{EBO} (V) Min	I _{CB0} (nA) @ V _{CB} (V) Max	h _{FE} @ I _C (mA) & V _{CE} (V)			V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) @ I _C (mA)		C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
						Min	Max			Min	Max		Min	Max					
MPSL01	TO-92 (92)	140	120	6	1 μA 40	50	300	10	5	0.2	1.2	10	8	60	10			16	
MPS8098	TO-92 (92)	60	0	6	100 60	100	300	1	5	0.3	1.4	50	6	150	10			18	
MPS8099	TO-92 (92)	80	80	6	100 60	100	300	1	5	0.3		100	6	150	10			18	
TIS98	TO-92 (97)		60		10 40	100	300	1	5	0.5		100		2	10			18	
TIS99	TO-92 (97)		65		10 40	55	300	100	5	0.5		100		2	10			18	
2N696	TO-5	60		5	1 μA 30	20	60	150	10	1.5	1.3	150	20	40	50			19	
2N697	TO-5	60	45	5	1 μA 30	40	120	150	10	1.5	1.3	150	35	50	50			19	
2N718	TO-18	60	30	5	1 μA 30	40	120	150	10	1.5	1.3	150	35	50	15			19	
2N718A	TO-18	75		7	10 60	20		500	10	1.5	1.3	150	25	60	50		12	1	19
						40	120	150	10										
						35		10	10										
						20		100 μA	10										
2N956	TO-18	75	35	7	10 60	40	300	150	10	1.5	1.3	150	25	70	50		8	1	19
						100		150	10										
						75		10	10										
						35		100 μA	10										
						20		10 μA	10										
2N1420	TO-5	60	30	5	1 μA 30	100	300	150	10	1.5	1.3	150	35	50	50				19
2N1566	TO-5	80	60	5	1 μA 40	80	200	5	5	1.0		10	10	60	5				19
2N2218	TO-5	60	30	5	10 50	20		500	10	0.4	1.3	150	8	250	20				19
						20		150	1										
						40	120	150	10	1.6	2.6	500							
						35		10	10										
						25		1	10										
						20		100 μA	10										
2N2218A	TO-5	75	40	6	10 60	25		500	10	0.3	0.6	1.2	8	250	20	285		2	19
						20		150	1										
						40	120	150	10										
						35		10	10										
						25		1	10										
						20		100 μA	10										

28C 35403 0

T-29-01

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

1-18



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) @ V _{CB} (V) Max	h _{FE} @ I _C & V _{CE} (V)			V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA)			C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
						Min	Max	@ I _C (mA)	Max	Min	Max		Min	Max					Min
2N2219	TO-5	60	30	5	10 50	30 50 100 75 50 35	500 150 300 10 1 100 μA	10 1 10 10 10 10	0.4 1.6	1.3 2.6	150 500	8	250	20					19
2N2219A	TO-5	75	40	6	10 60	40 50 100 75 50 35	500 150 300 10 1 100 μA	10 1 10 10 10 10		0.6 1.2 2	150 500	8	300	20	285		2		19
2N2221	TO-18	60	30	5	10 50	20 20 40 35 25 20	500 150 150 10 1 100 μA	10 1 10 10 10 10	0.4 1.6	1.3 2.6	150 500	8	250	20					19
2N2221A	TO-18	75	40	6	10 60	25 40 35 25 20	500 150 10 1 100 μA	10 10 10 10 10	0.3 1.0	0.6 2.0	150 500	8	250	20	285		2		19
2N2222	TO-18	60	30	5	10 50	30 50 100 75 50 35	500 150 300 10 1 100 μA	10 1 10 10 10 10	0.4 1.6	1.3 2.6	150 500	8	250	20					19
2N2222A	TO-18	75	40	6	10 60	40 50 100 75 50 35	500 150 300 10 1 100 μA	10 1 10 10 10 10	0.3 1	0.6 2	150 500	8	250	20	285	4	2/3		19
2N2897	TO-18	60		7	50 60	35 50	1 200	10 10	1	1.3	150	15							19

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CC} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CC} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz.

T-29-01

6501130 NATL SEMICOND, (DISCRETE)

28C 35404

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787

Http://www.100y.com.tw



NPN Transistors

0

1-19

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
 Http://www.100y.com.tw

NPN Transistors

6501130 NATL SEMICON, (DISCRETE)



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CEO} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) Max	V _{CB} (V)	hFE @ I _C & V _{CE} (V)			V _{CE(SAT)} (V) & V _{BE(SAT)} (V)			C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
							Min	Max	@	Max	Min	Max		@	Min					Max
2N3115	TO-18	60	20	5	25	50	40	120	150	10	0.5	1.3	150	8	250	20	500	2	19	
2N3116	TO-18	60	20	5	25	50	100	300	150	10	0.5	1.3	150	8	250	20	500	2	19	
2N3299	TO-5	60	30	5	10*	50	20		500	10	0.22	1.1	150	8	250	50	150		4	19
							20		150	1										
							40	120	150	10										
							35		10	10										
							25		1	10										
20		100 μA	10																	
2N3300	TO-5	60	30	5	10*	50	50		500	10	0.22	1.1	150	8	250	50	150		4	19
							50		150	1										
							100	300	150	10										
							75		10	10										
							50		1	10										
35		100 μA	10																	
2N3301	TO-18	60	30	5	10*	50	20		500	10	0.22	1.1	150	8	250	50	150		4	19
							20		150	1										
							40	120	150	10										
							35		10	10										
							25		1	10										
20		100 μA	10																	
2N3302	TO-18	60	30	5	10*	50	50		500	10	0.22	1.1	150	8	250	50	150		4	19
							50		150	1										
							100	300	150	10										
							75		10	10										
							50		1	10										
35		100 μA	10																	
2N3414	TO-92 (94)	25	25	5	100	25	75	225	2	4.5	0.3	0.6	1.3	50					19	
2N3641	TO-92 (92)	Same as PN3641, see page 1-22 for explanation																	19	
2N3642	TO-92 (92)	Same as PN3642, see page 1-22 for explanation																	19	
2N3643	TO-92 (92)	Same as PN3643, see page 1-22 for explanation																	19	
2N3678	TO-5	75	55	6	10	60	25		500	10	0.4	0.6	1.2	150			250		2	19
							20		150	1										
							40	120	150	10										
							35		10	10										
							25		1	10										
20		100 μA	10																	
2N4140	TO-92 (92)	Same as PN4140, see page 1-22 for explanation																	19	

1-20

28C 35405 D
 T-29-01



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) Max	V _{CB} (V)	h _{FE} @ I _C & V _{CE} (V)				V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA)				C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)			t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
							Min	Max	@	&	Max	Min	Max	@		I _C (mA)	Min	Max				
2N4141	TO-92 (92)	Same as PN4141, see page 1-22 for explanation																			19	
2N4969	TO-92 (92)	Same as PN2221, see below for explanation																			19	
2N4970	TO-92 (92)	50	30	5			100	350	150	10	0.4	0.6	1.2	150	8	200	20					19
							70		10	10												
							50		150	1												
2N5128	TO-92 (92)	Same as PN5128, see page 1-22 for explanation																			19	
2N5129	TO-92 (92)	Same as PN5129, see page 1-22 for explanation																			19	
2N5135	TO-92 (92)	Same as PN5135, see page 1-22 for explanation																			19	
2N5136	TO-92 (92)	Same as PN5136, see page 1-22 for explanation																			19	
2N5137	TO-92 (92)	Same as PN5137, see page 1-22 for explanation																			19	
PN2221	TO-92 (92)	60	30	5	10	50	20		500	10	0.4		1.3	150	8	250	20					19
							20		150	1												
							40	120	150	10	1.6		2.6	500								
							35		10	10												
							25		1	10												
							20		100 μA	10												
PN2221A	TO-92 (92)	75	40	6	10	60	25		500	10	0.3	0.6	1.2	150	8	250	20	285			2	19
							20		150	1												
							40	120	150	10	1.0		2.0	500								
							35		10	10												
							25		1	10												
							20		100 μA	10												
PN2222	TO-92 (92)	60	30	5	10	50	30		500	10	0.4		1.3	150	8	250	20					19
							50		150	1												
							100	300	150	10	1.6		2.6	500								
							75		10	1												
							50		1	1												
							35		100 μA	1												

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CC} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CC} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz.

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)



NPN Transistors

6501130 NATL SEMICON, (DISCRETE)

1-29-01

28C 35406

0

1-21

NPN Transistors

6501130 NATL SEMICOND, (DISCRETE)



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICBO (nA) @ VCB (V)	hFE			VCE(SAT) (V) Max	VBE(SAT) (V) @ IC (mA)			Cob (pF) Max	fT (MHz) @ IC (mA)		toff (ns) Max	NF (dB) Max	Test Conditions	Process No.																		
						Min	Max	@ IC (mA)		Min	Max	@ IC (mA)		Min	Max																						
PN2222A	TO-92 (92)	75	40	6	10 @ 60	40	500	10	0.3	0.6	1.2	150	8	300	20	285		2	19																		
						50	150	1																													
						100	300	150												10	1.0	2.0	500														
						75	10	1																													
						50	1	1																													
PN3641	TO-92 (92)	60*	30	5	50* @ 50	15	500	10	0.22			150	8	250	50				19																		
						40	120	150												10																	
						PN3642	TO-92 (92)	60												45	5	50* @ 50	15	500	10	0.22			150	8	250	50				19	
																							40	120	150												10
																							PN3643	TO-92 (92)	60												30
100	300	150	10																																		
PN4140	TO-92 (92)	60	30	5		20	500	10	0.4		1.3	150	8	250	20	310		2	19																		
						20	150	1																													
						40	120	150												10	1.6	2.6	500														
						35	10	10																													
						25	1	10																													
PN4141	TO-92 (92)	60	30	5		30	500	10	0.4		1.3	150	8	250	20	310		2	19																		
						50	150	1																													
						100	300	150												10	1.6	2.6	500														
						75	10	10																													
						50	1	10																													
PN5128	TO-92 (92)	15	12	3	50 @ 10	35	350	50	0.25		1.1	150	10	200	800	50				19																	
						20	10	10																													
PN5129	TO-92 (92)	15	12	3	50 @ 10	35	350	50	0.25		1.1	150	10	200	800	50				19																	
						20	10	10																													
PN5135	TO-92 (92)	30	25	4	300 @ 15	50	60*	10	1.0		1.0	100	25	40	500	30				19																	
						15	2	10																													
PN5136	TO-92 (92)	30	20	3	100 @ 20	20	400	150	0.25		1.1	150	35	40	400	50				19																	
						20	30	1																													
PN5137	TO-92 (92)	30	20	3	100 @ 20	20	400	150	0.25		1.1	150	35	40	400	50				19																	
						20	30	1																													
TN2218A	TO-237 (91)	75	40	6	10 @ 60	25	500	10	0.3	0.6	1.2	150	8	250	20	285		2	19																		
						20	150	1																													
						40	120	150												10	1.0	2.0	500														
						35	10	10																													
						25	1	10																													
						20	100 μ A	10																													

1-22

28C 35407 D
T-29-01

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
 Http://www.100y.com.tw



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) @ V _{CB} (V) Max	h _{FE} @ I _C & V _{CE} (V)			V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA)			C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.					
						Min	Max	I _C (mA)	V _{CE} (V)	Max	Min		Max	I _C (mA)					Min	Max			
TN2219	TO-237 (91)	60	30	5	10 50	30	500	10	0.4	1.3	150	8	50	20				19					
						50	150	1	1.6	2.6	500												
						100	300	150											10				
						75	10	10															
						50	1	10															
35	0.1	10																					
TN2219A	TO-237 (91)	75	40	6	10 60	40	500	10	0.3	0.6	1.2	8	60	20		4	3	19					
						50	150	1	1.0	2.0	500												
						100	300	150											10				
						75	10	10															
						50	1	10															
35	0.1	10																					
TIS90	TO-92 (94)	40	40	5	100 20	100	300	50	2	0.25	0.6	1	50						19				
TIS92	TO-92 (97)	40	40	5	100 20	100	300	50	2	0.25	0.6	1	50						19				
2N915	TO-18	70	50	5	10 60	50	200	10	5	1.0	0.9	10	3.5	250	10				23				
2N916	TO-18	45	25	5	10 30	50	200	10	1	0.5	0.9	10	6	300	10				23				
2N3691	TO-92 (92)	Same as PN3691, see page 1-25 for explanation															23						
2N3692	TO-92 (92)	Same as PN3692, see page 1-25 for explanation															23						
2N3903	TO-92 (92)	60	40	6		15	100	1	0.2	0.6	0.85	10	4	250	10	225	6	6/7	23				
						30	50	1															
						50	150	10												1	0.3	0.95	50
						35	1	1															
						20	100 μA	1															
2N3904	TO-92 (92)	60	40	6	30	30	100	1	0.2	0.65	0.85	10	4	300	10	250	5	6/7	23				
						60	50	1															
						100	300	10												1	0.3	0.95	50
						70	1	1															
						40	100 μA	1															
2N3946	TO-18	60	40	6		20	50	1	0.2	0.6	0.9	10	4	250	10	375	5	6/7	23				
						50	150	10												1			
						45	1	1												0.3	1.0	50	
						30	100 μA	1															

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CC} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CC} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz.

1-23

6501130 NATL SEMICOND, (DISCRETE)

T-29-01
28C 35408

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)



PNP Transistors

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

NPN Transistors

6501130 NATL SEMICOND, (DISCRETE)



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0}	V _{CE0}	V _{EB0}	I _{CB0}	V _{CB}	h _{FE}			I _C & V _{CE}	V _{CE(SAT)} & V _{BE(SAT)}			I _C	C _{ob}	f _T		t _{off}	NF	Test Conditions	Process No.		
		(V) Min	(V) Min	(V) Min	(nA) Max		(V)	Min	Max		@ I _C (mA)	(V) Max	(V) Min			(V) Max	(pF) Max					(MHz) Min	(MHz) Max
2N3947	TO-18	60	40	6			40	100	300	50	10	1	0.2	0.6	0.9	10	4	300	10	450	5	6/7	23
							90			1	1	1	0.3		1.0	50							
							60			100	μA	1											
2N4123	TO-92 (92)	40	30	5	50	20	25	50	150	50	2	1	0.3	0.95	50	4	250	10		6	7	23	
2N4124	TO-92 (92)	30	25	5	50	20	60	120	360	50	2	1	0.3	0.95	50	4	300	10		5	7	23	
MPS2711	TO-92 (92)	18	18	5	500	18	30	90		2		4.5				4						23	
MPS2712	TO-92 (92)	18	18	5	500	18	75	225		2		4.5				4						23	
MPS2716	TO-92 (92)	18	18	5	500	18	75	225		2		4.5				3.5						23	
MPS2923	TO-92 (92)	25	25	5	500	25	90	180		2		10				12						23	
								(1 kHz)															
MPS2924	TO-92 (92)	25	25	5	500	25	150	300		2		10				12						23	
								(1 kHz)															
MPS2925	TO-92 (92)	25	25	5	500	25	235	470		2		10				12						23	
								(1 kHz)															
MPS2926	TO-92 (92)	25	25	5	500	18	35	470		2		10				3.5						23	
								(1 kHz)															
MPS3642	TO-92 (92)	Same as PN3642, see page 1-22 for explanation																			23		
MPS3721	TO-92 (92)				500	18	60	660		2		10				3.5						23	
								(1 kHz)															
MPS3826	TO-92 (92)	60	45	4	100	30	40	160		10		10				3.5	200	800	10			23	
MPS3827	TO-92 (92)	60	45	4	100	30	100	400		10		10				3.5	200	800	10			23	
MPS6512	TO-92 (92)	40	30	4	50	30	30	100		2		10	0.5		50	3.5						23	
MPS6513	TO-92 (92)	40	30	4	50	30	60	100		2		10	0.5		50	3.5						23	
MPS6514	TO-92 (92)	40	25	4	50	30	90	150		2		10	0.5		50	3.5						23	
MPS6515	TO-92 (92)	40	25	4	50	30	150	250		2		10	0.5		50	3.5						23	

1-24

28C 35409 D
 T-29-01



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (nA) Max	V _{CB} (V) @	h _{FE} @ I _C & V _{CE} (V)			V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA)			C _{ob} (pF) Max	f _T (MHz) @ I _C (mA)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.					
							Min	Max	@	Max	Min	Max		Min	Max					Min	Max			
NS3903	TO-18	60	40	6			15	100	1	0.2	0.65	0.85	10	4	250	10	225		6	23				
							30	50	1															
							50	150	10												1	0.3	0.95	50
							35	1	1															
							20	100 μA	1															
NS3904	TO-18	60	40	6			30	100	1	0.2	0.65	0.85	10	4	300	10	250		6	23				
							60	50	1															
							100	300	10												1	0.3	0.95	50
							70	1	1															
							40	100 μA	1															
PN3691	TO-92 (92)	35	20	4	50	15	40	160	10	1	0.7	0.9	10	3.5	200	500	10			23				
PN3692	TO-92 (92)	35	20	4	50	15	100	400	10	1	0.7	0.9	10	3.5	200	500	10			23				
ST3904	TO-92 (92)	60	40	6			40	0.1	1	0.2	0.65	0.85	10	4	300	10		8	7	23				
							70	1	1															
							100	300	10												1	0.3	0.95	50
							60	50	1															
							30	100	1															
2N2712	TO-92 (94)	18	18	5	500	18	75	225	2	4.5				12	80	300	2			27				
2N2714	TO-92 (94)	18	18	5	500	18	75	225	2	4.5	0.3	0.6	1.2	50						27				
2N3394	TO-92 (94)	25	25	5	100	18	55	110	2	4.5				10						27				
2N3693	TO-92 (92)	Same as MPS3693, see page 1-26 for explanation																	27					
2N3694	TO-92 (92)	Same as PN3694, see page 1-26 for explanation																	27					
2N3721	TO-92 (94)	18	18	5	500	18	60	660	2	10				12						27				
2N3827	TO-92 (94)	60	45	4	100	30	100	400	10	10				3.5	200	800	10			27				
2N3858	TO-92 (94)	30	30	4	500	18	60	120	2	4.5				4	90	250	2			27				

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CC} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CC} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz.

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)



JPN Transistors

6501130 NATL SEMICON. (DISCRETE)

28C 35410

1-29-01

1-25

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

NPN Transistors

6501130 NATL SEMICOND. (DISCRETE)

28C 35411

Y-29-01



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

Type No.	Case Style	V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} (mA) Max	V _{CB} (V)	h _{FE} @ I _C & V _{CE}				V _{CE(SAT)} & V _{BE(SAT)} @ I _C			C _{ob} (pF) Max	f _T @ I _C			t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
							Min	Max	@	(mA)	&	(V)	Max		Min	Max	@				
2N3859	TO-92 (94)	30	30	4	500	18	100	200	2	4.5			4	90	250	2					27
2N3860	TO-92 (94)	30	30	4	500	18	150	300	2	4.5			4	90	250	2					27
2N5127	TO-92 (92)	Same as PN5127, see below for explanation																			27
2N5131	TO-92 (92)	Same as PN5131, see below for explanation																			27
2N5132	TO-92 (92)	Same as PN5132, see below for explanation																			27
2N5219	TO-92 (92)	20	15	3	100	10	35	500	2	10	0.4	1.0	10	4	150	10					27
2N5223	TO-92 (92)	25	20	3	100	10	50	800	2	10	0.7	1.2	10	4	150	10					27
MPS3693	TO-92 (92)	45	45	4	50	35	40	160	10	10			3.5	200	10		4		9		27
MPS3694	TO-92 (92)	45	45	4	50	35	100	400	10	10			3.5	200	10		4		9		27
MPS6564	TO-92 (92)		45	5	500	40	25		10	5	0.5		10	4							27
MPS6565	TO-92 (92)	60	45	4	100	30	40	160	10	10	0.4		10	3.5							27
MPS6566	TO-92 (92)	60	45	4	100	30	100	400	10	10	0.4		10	3.5	200	10					27
MPSA10	TO-92 (92)		40	4	100	30	40	400	5	10			4	50	5						27
PN3694	TO-92 (92)	45	45	4	50	30	100	400	10	1			6	200	10						27
PN5127	TO-92 (92)	20	12	3	50	10	15	300	2	10	0.3	1.0	10	3.5	150	2					27
PN5131	TO-92 (92)	20	15	3	50	10	35	500	10	1	1.0		10	6	100	10					27
PN5132	TO-92 (92)	20	20	3	50	10	30	400	10	10	2.0	0.9	10	3.5	200	10					27

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1 kHz. (2) I_C = 150 mA, V_{CC} = 30V, I_B¹ = I_B² = 15 mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 300 mA, V_{CC} = 25V, I_B¹ = I_B² = 30 mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7 kHz. (6) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7 kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10 Hz-15.7 kHz. (9) I_C = 3 mA, V_{CE} = 10V, f = 1 MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz.

1-26

D